# NSN 5962-01-177-2209

Memory Microcircuit - Page 1 of 1



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## **Body Length:**

Between 0.882 inches and 0.925 inches

#### **Body Width:**

0.310 inches

# **Body Height:**

Between 0.145 inches and 0.175 inches

# **Maximum Power Dissipation Rating:**

600.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and 3-state output and bipolar and programmable

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

16 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

80.00 nanoseconds propagation delay time, low to high level output

## Memory Device Type:

Rom

## **Terminal Type And Quantity:**

28 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

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